

## Coulomb-blockaded Josephson junction as a noise detector

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### 1. Introduction

The behavior of a Josephson junction is strongly influenced by the dissipation caused by the resistance  $R$  of the surrounding environment.<sup>1)</sup> If dissipation is small ( $R > R_Q = h/4e^2$ ), the phase of the junction becomes delocalized by fluctuations, and Coulomb blockade (CB) of Cooper pair tunneling takes place.<sup>1-3)</sup> In this case, theory predicts a power-law-like increase of conductance, both as a function of temperature and voltage.<sup>1)</sup> The exponent of the power law,  $2\rho - 2$ , is specified by the parameter  $\rho = R/R_Q$ . Hence, in the case of large exponents  $2\rho - 2 \gg 1$ , the conductance is highly susceptible to tiny changes in temperature, or alternatively, there is a high sensitivity to any extra noise sources.

We have investigated if this extreme sensitivity could be turned into use in a high-resolution noise detector. For this purpose, we have experimentally investigated how the CB of a Josephson junction changes in the presence of shot noise induced by a near-by SIN junction. In this brief note, we will discuss just one of our samples and present the basic findings on it. For a more detailed description, we refer to a forthcoming publication Ref.<sup>4)</sup>

### 2. Experiment

The schematic structure of our sample is displayed in Fig. 1. The circuit consists of: 1) an Al-AlO<sub>x</sub>-Al Josephson junction (JJ) with a tunnel resistance of  $R_T^{JJ} = 8.1$  k $\Omega$ , 2) a superconducting-normal Al-AlO<sub>x</sub>-Cu tunnel junction (SIN) with  $R_T^{SIN} = 27.3$  k $\Omega$ , and 3) a thin film Cr resistor of  $R_C = 22.6$  k $\Omega$  (20  $\mu$ m long), located within a few  $\mu$ m from the Josephson junction.

The sample was patterned using electron beam lithography and four-angle shadow evaporation. The Cr resistor (5 nm thick, 100 nm wide) was evaporated first at an angle of  $-18^\circ$ , followed by the Al-island at  $-38^\circ$ . After oxidation, the sample holder was rotated by  $45^\circ$  around the z-axis and the JJ was deposited by a second Al-evaporation at  $+38^\circ$ . Last, the SIN-junction was formed by a copper deposition at  $+6^\circ$ .

The JJ junction was, in fact, made of two 100\*100 nm<sup>2</sup> junctions in a SQUID geometry. In all noise studies reported here, the Josephson energy was tuned to its minimum value of  $E_J = 22$   $\mu$ eV. The minimum Joseph-

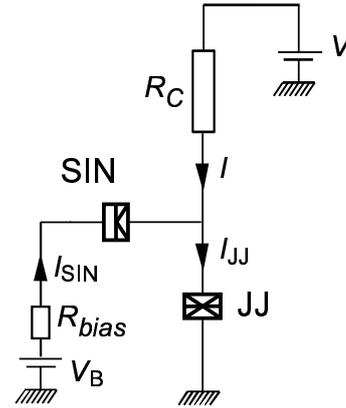


Fig. 1. Scheme of the experimental circuit. The high impedance environment, given by a chrome resistor, is denoted by  $R_C$ , the superconductor-normal metal junction by SIN, the Josephson junction by JJ. Symbols for different biasing voltages and the resulting currents are also given in the figure.

son coupling energy,  $E_J^{min}$ , was obtained from the minimum of critical current  $I_C(\Phi)$  as a function of external flux  $\Phi$  by assuming a linear dependence between  $E_J$  and  $I_C$ ; the maximum value  $E_J^{max}$  was calculated using the Ambegaokar-Baratoff relation. The Coulomb energy  $E_C = e^2/2C = 65$   $\mu$ eV was estimated from the asymptotic IV-curves in the normal state. Thus, the ratio  $E_J/E_C = 0.34$ . The measurement leads were filtered by 1.5 MHz low-pass filters at the top of the cryostat and by 1 m of Thermocoax cable at the mixing chamber temperature.

### 3. Results

The IV-curve of our sample is displayed in Fig. 2 where we plot the current through the chrome resistor  $I$  as a function of the full transport voltage  $V$ . Near zero-bias, a clear Coulomb blockade of the Cooper pair current is seen. The behavior of the Coulomb blockade follows well the expectations from the theory, *i.e.*, we observe a steep power law as a function of  $T$ .<sup>4)</sup> At higher voltages, Zener tunneling up to higher bands sets in, which leads to a decrease in the rate of Cooper pair tunneling. The dashed line displays the IV-curve under the influence of a small base current  $I_{SIN} = 0.4$  nA. It is seen to suppress the Coulomb blockade strongly while the Zener tunneling region is only mildly influenced by the added quasiparticle current.

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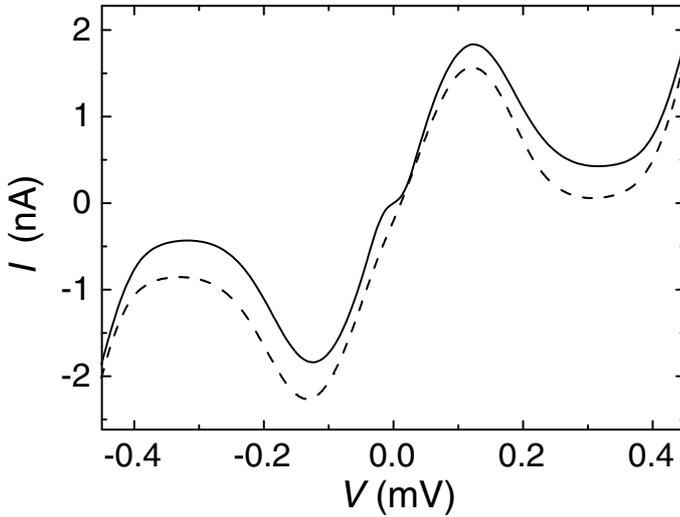


Fig. 2. Solid curve displays an IV-curve measured at  $T = 90$  mK. The dashed curve illustrates the IV-curve under otherwise the same conditions but with  $I_{SIN} = 0.4$  nA ( $R_{bias} = 100$  M $\Omega$ ).

Experimentally, it is easier to quantify the effect of the base current by measuring the dynamic resistance  $R = \frac{dV}{dI_{JJ}}$ . This quantity is shown in Fig. 3, where we compare the effect of  $I_{SIN}$  to that of  $T$ . From the shapes of the RV-curves measured at  $T = 90$  and 130 mK, we deduce that a current of  $I_{SIN} = 0.1$  nA produces a similar effect as a temperature change of  $\Delta T = 40$  mK.

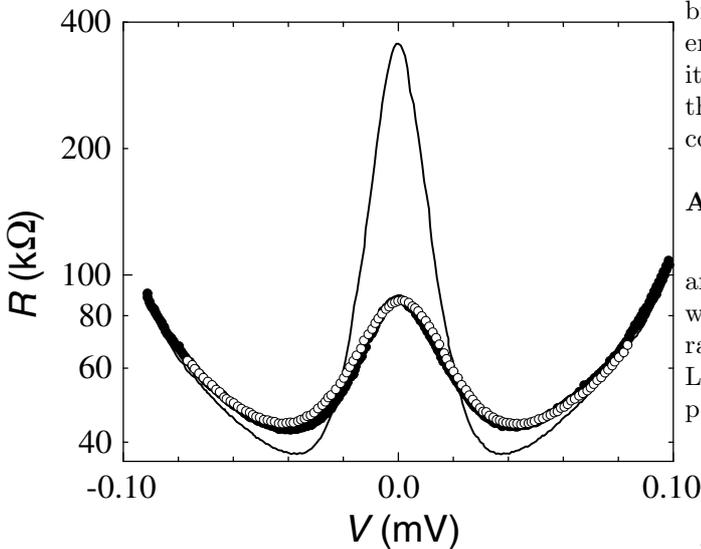


Fig. 3. Influence of  $I_{SIN}$  and  $T$  on the differential resistance  $R = \frac{dV}{dI_{JJ}}$  around the Coulomb-blockaded region. Solid curve –  $T = 90$  mK and  $I_{SIN} = 0$ ; open circles –  $T = 130$  mK and  $I_{SIN} = 0$ ; filled circles –  $T = 90$  mK and  $I_{SIN} = 0.1$  nA. Voltage scales of the curves have been slightly modified in order allow for a better comparison.

#### 4. Discussion

At present, there is no well-developed theory for the behavior of a Coulomb-blockaded Josephson junction under the influence of shot noise. Assuming that the

shot noise from the SIN-junction can be converted to an equivalent resistive noise source,<sup>5)</sup> one can estimate the

Fano-factor of the current-induced noise:

$$F = \frac{2k_B\Delta T}{eI_{SIN}R_C}. \quad (1)$$

It can be shown<sup>4)</sup> using the  $P(E)$  formalism for inelastic Cooper pair tunneling<sup>6,7)</sup> that, in the superconducting phase ( $\rho \ll 1$ ), the above approach is sound whereas in the insulating phase ( $\rho \gg 1$ ) it must be considered as approximative, and one should resort to numerical analysis. The comparison of the data sets in Fig. 3 suggests that  $F \sim 3$  for our sample.

Part of the deviation from  $F \sim 1$  may be attributed to the fact that a SIN junction is a complicated nonlinear object. In the subgap region, Andreev reflection plays a role, which should lead to  $F = 2$  since, instead of single electrons, there is tunneling of Cooper pairs with a charge of  $2e$ .

#### 5. Conclusions

Altogether, a Josephson junction noise detector provides a serious alternative to be considered for high-resolution noise measurements. Its main virtue, the high sensitivity, comes from the large detector band width:  $\sim 1/R_C C$ . However, as long as a detailed noise theory for the case under consideration is lacking, a calibration source with a known power spectrum should be employed. A junction detector will surpass the sensitivity of regular high-resolution noise measurements<sup>8)</sup> when the selection of the parameter values and the operating conditions are properly made.<sup>4)</sup>

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